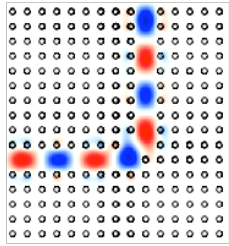
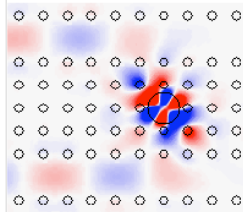


# “1d” Waveguides + Cavities = Devices

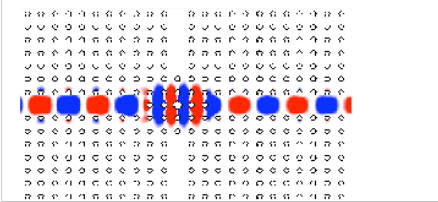
high transmission through sharp bends



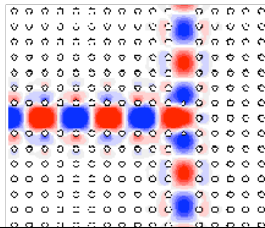
channel-drop filter



elimination of waveguide crosstalk

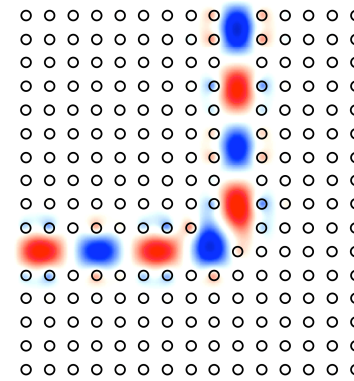


high transmission in wide-angle splitters

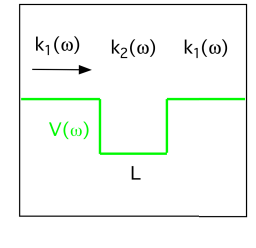


# Lossless Bends

100% Transmission through Sharp Bends



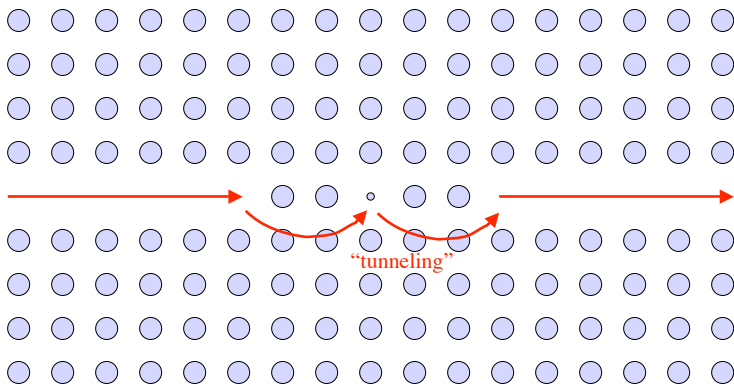
Maps onto problem of  
Electron Resonant  
Scattering in 1D



[ A. Mekis et al.,  
*Phys. Rev. Lett.* **77**, 3787 (1996) ]

symmetry + single-mode + “1d” = resonances of 100% transmission

# Waveguides + Cavities = Devices

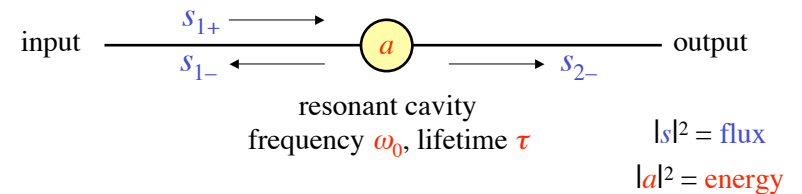


Ugh, must we simulate this to get the basic behavior?

# “Coupling-of-Modes-in-Time”

(a form of coupled-mode theory)

[H. Haus, *Waves and Fields in Optoelectronics*]



$$\frac{da}{dt} = -i\omega_0 a - \frac{2}{\tau} a + \sqrt{\frac{2}{\tau}} s_{1+}$$

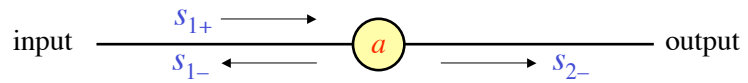
$$s_{1-} = -s_{1+} + \sqrt{\frac{2}{\tau}} a, \quad s_{2-} = \sqrt{\frac{2}{\tau}} a$$

assumes only:

- exponential decay
- (strong confinement)
- conservation of energy
- time-reversal symmetry

# “Coupling-of-Modes-in-Time” (a form of coupled-mode theory)

[H. Haus, *Waves and Fields in Optoelectronics*]

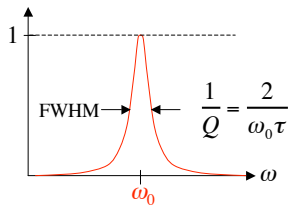


resonant cavity  
frequency  $\omega_0$ , lifetime  $\tau$

$|s|^2 = \text{flux}$

$|a|^2 = \text{energy}$

transmission  $T$   
 $= |s_{2-}|^2 / |s_{1+}|^2$

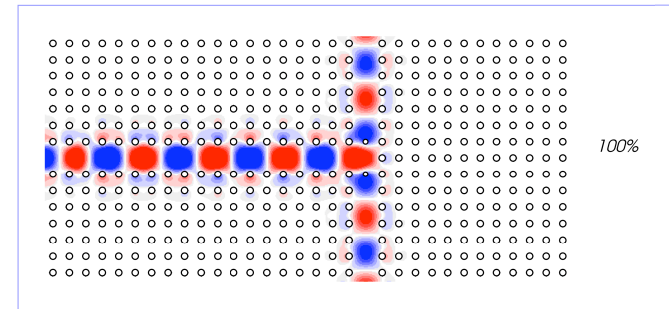
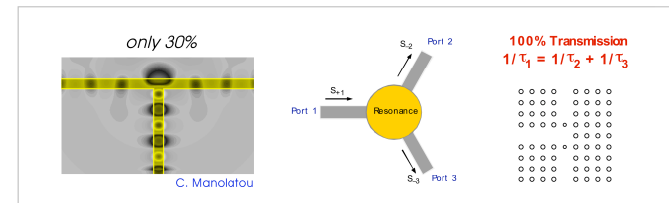


$T = \text{Lorentzian filter}$

$$= \frac{\frac{4}{\tau^2}}{(\omega - \omega_0)^2 + \frac{4}{\tau^2}}$$

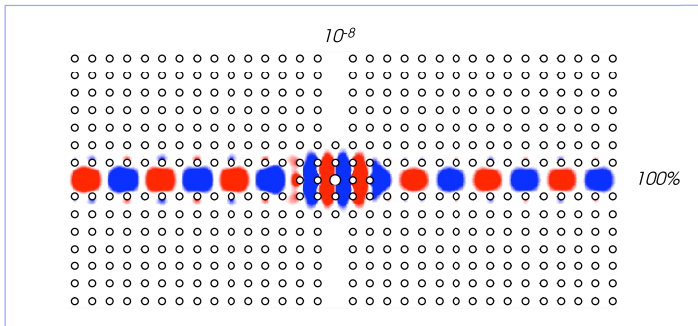
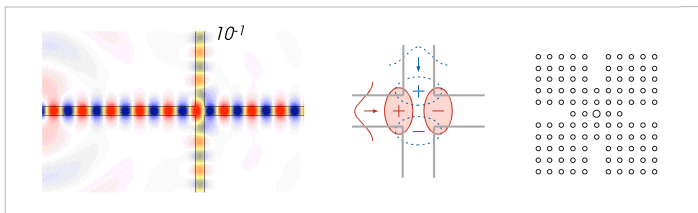
...quality factor  $Q$

# Wide-angle Splitters



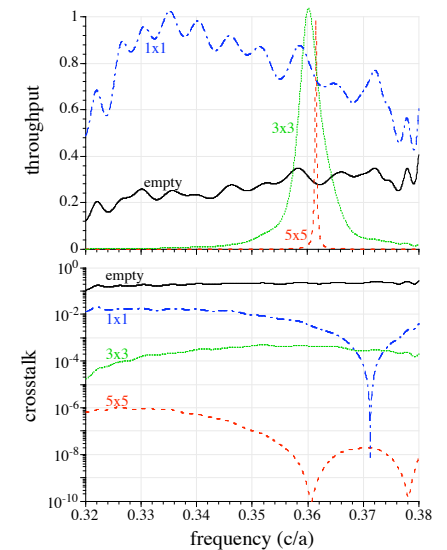
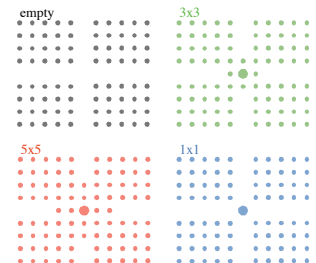
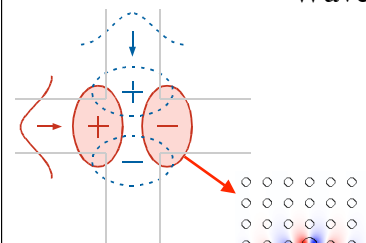
[ S. Fan *et al.*, *J. Opt. Soc. Am. B* **18**, 162 (2001) ]

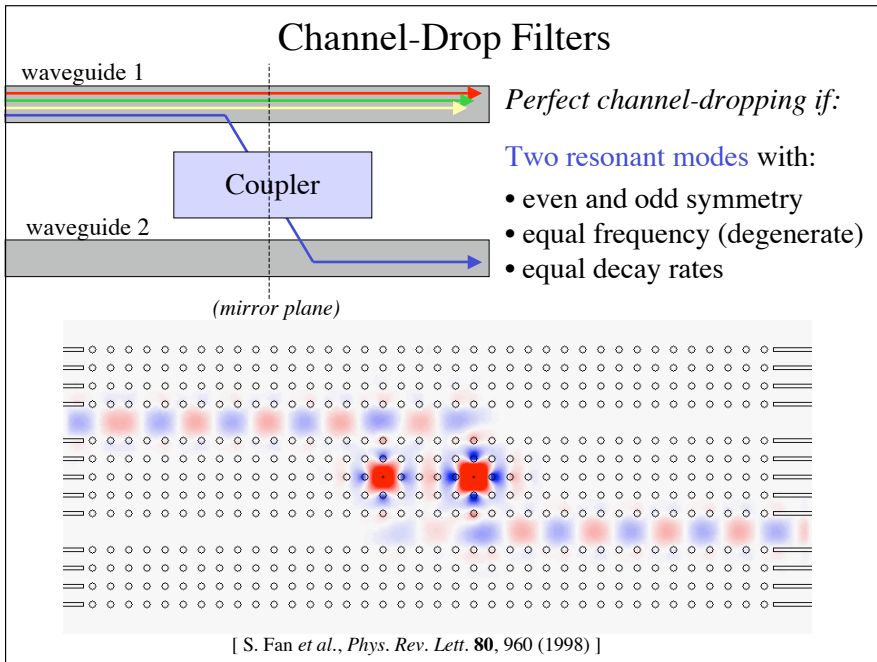
# Waveguide Crossings



[ S. G. Johnson *et al.*, *Opt. Lett.* **23**, 1855 (1998) ]

# Waveguide Crossings





## Enough passive, linear devices...

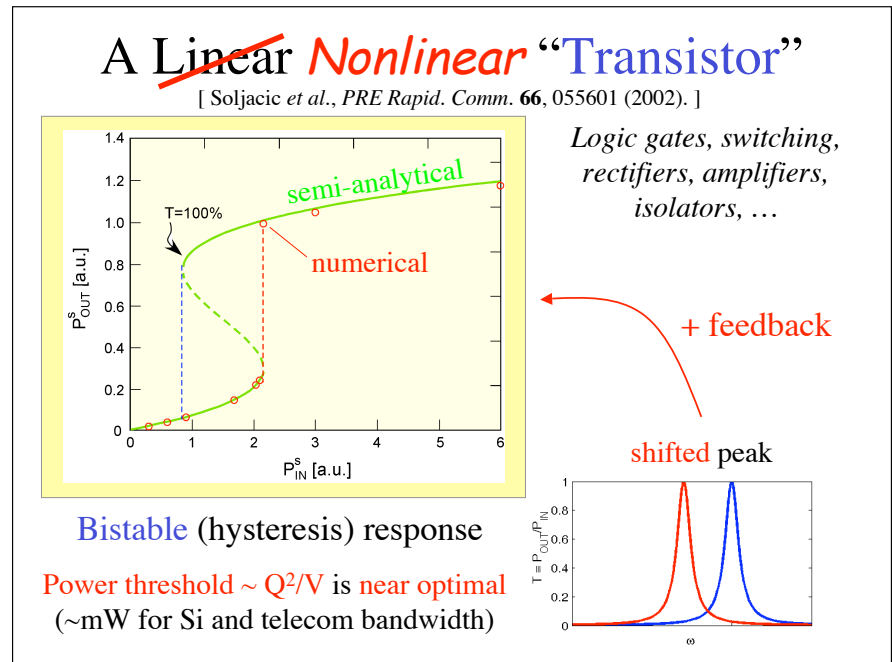
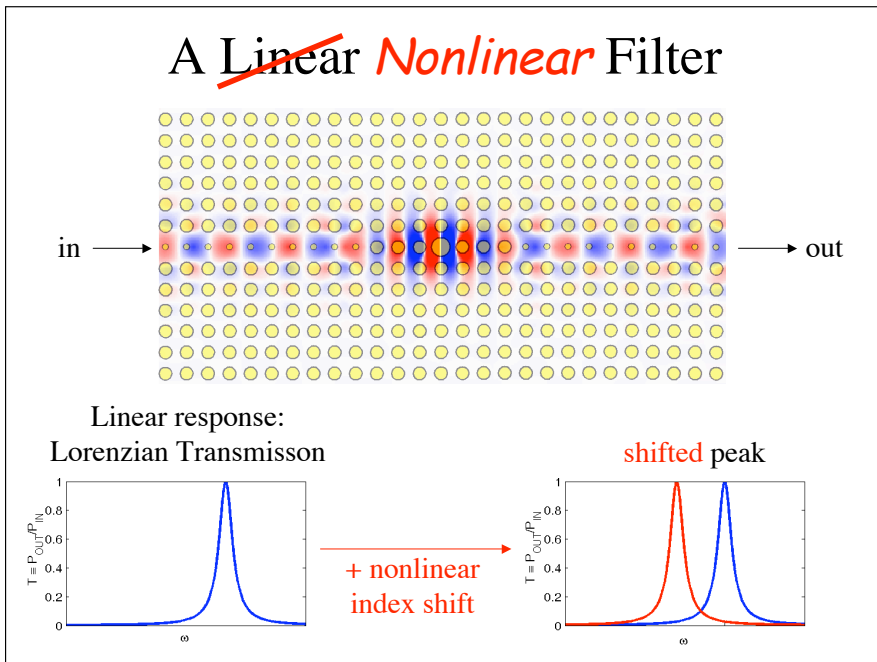
Photonic crystal cavities:

tight confinement ( $\sim \lambda/2$  diameter)

+ long lifetime (high  $Q$  independent of size)

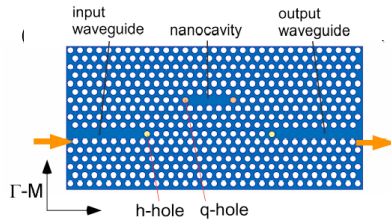
**= enhanced nonlinear effects**

e.g. Kerr nonlinearity,  $\Delta n \sim$  intensity

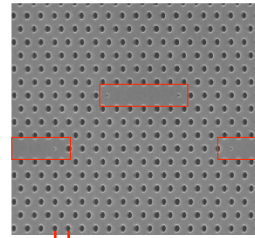


# Experimental Bistable Switch

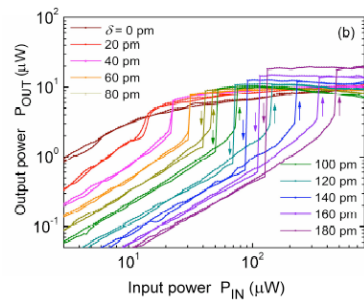
[ Notomi *et al.*, *Opt. Express* **13** (7), 2678 (2005). ]



Silicon-on-insulator



420 nm



$Q \sim 30,000$   
Power threshold  $\sim 40 \mu\text{W}$   
Switching energy  $\sim 4 \text{ pJ}$